

Voltage Variable Absorptive Attenuator

DC - 2 GHz

AT-259

V 2.00

Features

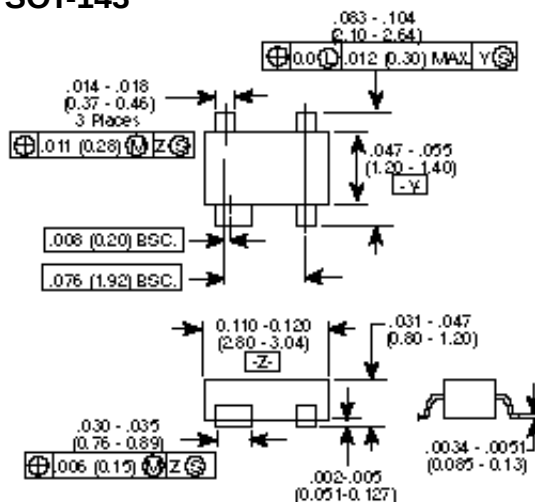
- Attenuation: 12 dB at 1 GHz
- Low Intermodulation Products
- Low DC Power Consumption: 50 μ W
- Single Voltage Control 0 to -4 Volts
- Nanosecond Switching Speed
- Temperature Range: -40°C to + 85°C
- Low Cost SOT/143 Plastic Package
- Tape and Reel Packaging Available¹

Description

M/A-COM's AT-259 is a GaAs MMIC voltage variable absorptive attenuator in a low cost SOT/143 4-Lead surface mount plastic package. The AT-259 is ideally suited for use where attenuation fine tuning, fast switching and very low power consumption are required. Typical applications include radio, cellular, GPS equipment and other Automatic Gain/Level Control circuits.

The AT-259 is fabricated with a monolithic GaAs MMIC using a mature 1 micron process. The process features full chip passivation for increased performance and reliability.

SOT-143



SOT-143 outline dimensions
(All dimensions per JEDEC No. TO-253 Issue C)
Dimensions in () are in mm.
Unless Otherwise Noted: .xxx = ± 0.10 (.xx = ± 0.25)
.xxx = ± 0.02 (.x = ± 0.5)

Ordering Information

Part Number	Package
AT-259 PIN	SOT 4-Lead Plastic Package
AT-259TR	Forward Tape & Reel
AT-259RTR	Reverse Tape & Reel

Electrical Specifications, $T_A = +25^\circ\text{C}$

Parameter	Test Conditions ²	Unit	Min.	Typ.	Max
Insertion Loss	DC - 0.1 GHz	dB		2.9	3.1
	DC - 0.5 GHz	dB		3.0	3.2
	DC - 1.0 GHz	dB		3.2	3.5
	DC - 2.0 GHz	dB		3.4	3.8
Flatness (Peak to Peak)	DC - 2.0 GHz	dB		± 0.2	± 0.4
	5 dB Attenuation	dB		± 2.3	± 2.5
	10 dB Attenuation	dB		± 7.0	± 7.5
VSWR				2.1:1	
Trise, Tfall Ton, Toff Transients	10% to 90% RF, 90% to 10% RF	nS		3	
	50% Control to 90% RF, 50% Control to 10% RF	nS		5	
	In Band	mV		10	
Power Handling	Linear Operation	dBm			13
	Absolute Max. Input Power	dBm			21
IP ₂	Measured Relative to Input Power (For two-tone Input Power Up to +5 dBm)	dBm		34 47	
IP ₃	Measured Relative to Input Power (For two-tone Input Power Up to +5 dBm)	dBm dBm	18 18.5	31 ⁽³⁾ 36 ⁽³⁾	

1. Refer to "Tape and Reel Packaging" Section, or contact factory.

2. All measurements at 1 GHz in a 50W system, unless otherwise specified. A control voltage 0 to -4 volts @ 20 μ A typ.

3. For levels above 6 dB attenuation. For levels below 6 dB, the minimum specification numbers apply.

Absolute Maximum Ratings¹

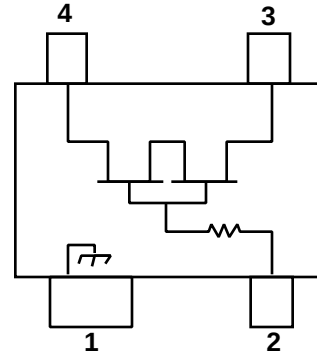
Parameter	Absolute Maximum
Max. Input Power	+21 dBm
Control Voltage	+5 V, -8.5 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

1.Operation of this device above any one of these parameters may cause permanent damage

Pin Configuration

Pin No.	Description
1	GND
2	A
3	RF2
4	RF1

Functional Schematic



Typical Performance

